

Features

- High current capacity in compact package Ic = -1.5A
- Epitaxial planar type
- Pb-free package is available
- Suffix "-H" indicates Halogen-free part

Mechanical data

• Epoxy:UL94-V0 rated flame retardant

• Case: Molded plastic, SOT-23

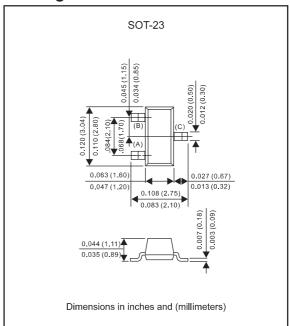
• Terminals : Solder plated, solderable per

MIL-STD-750, Method 2026

• Mounting Position : Any

• Weight: Approximated 0.008 gram

Package outline



Maximum ratings (AT T_A=25°C unless otherwise noted)

PARAMETER	Symbol	Value	UNIT
Collector-base voltage	V _{CBO}	-40	V
Collector-emitter voltage	V _{CEO}	-25	V
Emitter-base voltage	V _{EBO}	-5.0	V
Collector current-continuoun	I _c	- 1500	mAdc

Thermal characteristics

PARAMETER	Symbol	MIN.	TYP.	MAX.	UNIT	
Total device dissipation FR-5 board	$T_A = 25^{\circ}C$	P _D			225	mW
(1)	Derate above 25°C				1.8	mW/°C
Thermal resistance	Junction to ambient	$R_{\theta JA}$			556	°C/W
Total device dissipation alumina	$T_A = 25^{\circ}C$	P _D			300	mW
substrate(2)	Derate above 25°C				2.4	mW/°C
Thermal resistance	Junction to ambient	$R_{\scriptscriptstyle ext{ hetaJA}}$			417	°C/W
Operating junction temperature range			-55		+150	°C
Storage temperature range	T _{STG}	-55		+150	°C	

^{1.}FR-5 = 1.0 X 0.75 X0.062 in.

2.Alumina = 0.4 X 0.3 X 0.024 in. 99.5% alumina.



Electrical characteristics (AT T_A=25°C unless otherwise noted)

Off characteristics

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Collector-base breakdown voltage	I _c = -100uA	V _{(BR)CBO}	-40			V
Collector-emitter breakdown voltage	I _c = -1.0mA	$V_{(BR)CEO}$	-25			V
Emitter-base breakdown voltage	I _E = -100uA	V _{(BR)EBO}	-5.0			V
Collector cutoff current	V _{CB} = -35V	Сво			-150	nA
Emitter cutoff current	V _{EB} = -4.0V	I _{EBO}			-150	nA

On characteristics

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
DC current gain	I _c = -100mA, V _{CE} = -1.0V	h _{FE} *Note	100		600	
Collector-emitter saturation voltage	$I_c = -800 \text{mA}, I_B = -80 \text{mA}$	V _{CE(sat)}			-0.5	V

Note	*	١	Ι	J	
	hfe	120~200	200~350	300~400	



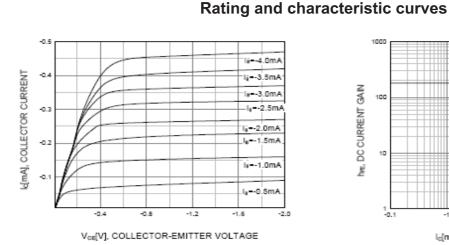


Figure 1. Static Characteristic

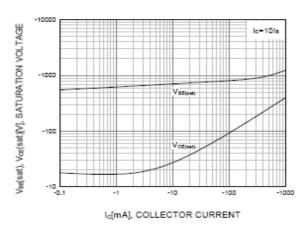


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

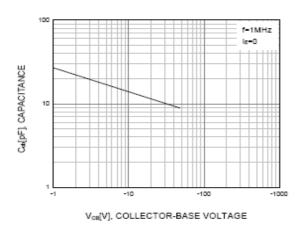


Figure 5. Collector Output Capacitance

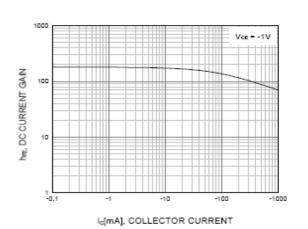


Figure 2. DC current Gain

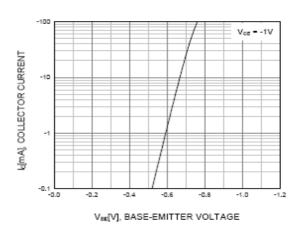


Figure 4. Base-Emitter On Voltage

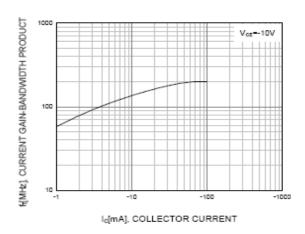


Figure 6. Current Gain Bandwidth Product



Pinning information

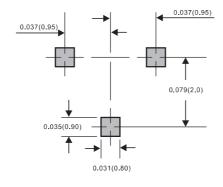
Pin	Simplified outline	Symbol
PinB Base PinC Collector PinE Emitter	C H B E	B O E

Marking

Type number	Marking code
SS8550	Y2

Suggested solder pad layout

SOT-23



Dimensions in inches and (millimeters)

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOT-23	7"	3,000	4.0	30,000	183*123*183	178	382*257*387	240,000	11.6

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